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UNITED STATES DEPARTMENT OF COMMERCE
Patent and Trademark Office

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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.
09/730,875	12/05/00	ISHIDA	S 2933SE-64-CO

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MM41/1025

EXAMINER

LOKE, S

ART UNIT

PAPER NUMBER

2811

DATE MAILED: 10/25/01

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner of Patents and Trademarks

Office Action Summary

Application No.

09/730,875

Applicant(s)

ISHIDA ET AL.

Examiner

Steven Loke

Art Unit

2811

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 05 December 2000.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
- Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- 11) ☐ The proposed drawing correction filed on _____ is: a) ☐ approved b) ☐ disapproved by the Examiner.
- If approved, corrected drawings are required in reply to this Office action.
- 12) ☐ The oath or declaration is objected to by the Examiner.

Priority under 35 U.S.C. §§ 119 and 120

- 13) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☒ Certified copies of the priority documents have been received in Application No. 09/024,855.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- * See the attached detailed Office action for a list of the certified copies not received.
- 14) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).
- a) ☐ The translation of the foreign language provisional application has been received.
- 15) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

Attachment(s)

- 1) ☒ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☒ Information Disclosure Statement(s) (PTO-1449) Paper No(s) 2.
- 4) ☐ Interview Summary (PTO-413) Paper No(s) _____.
- 5) ☐ Notice of Informal Patent Application (PTO-152).
- 6) ☐ Other:

The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

Claim 1 is rejected under 35 U.S.C. 112, first paragraph, as containing subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention.

The written description never discloses the polycrystalline silicon film being formed by irradiating a laser beam on a surface of an amorphous silicon film to heat the amorphous film as claimed in claim 1.

The written description never discloses the laser beam is scanned on the surface of the amorphous silicon film such that laser energy increases in order of the substrate, one of the pair of tapered end portions, and the center portion as claimed in claim 1.

Claim 1 is rejected under 35 U.S.C. 112, first paragraph, as containing subject matter which was not described in the specification in such a way as to enable one skilled in the art to which it pertains, or with which it is most nearly connected, to make and/or use the invention.

The specification also never discloses how a uniform grain size of the polycrystalline silicon film is acquired by securing a gate withstand voltage of the thin film transistor and preventing the inclined surfaces of the pair of tapered end portions from increasing as claimed in claim 1.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

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(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

Claim 1 insofar, as in compliance with 35 USC 112, is rejected under 35 U.S.C. 103(a) as being unpatentable over Tsai et al. in view of Ono et al. (PTO-1449).

Tsai et al. discloses a thin film transistor in fig. 11. It comprises: an insulator substrate [71]; a gate electrode [72] located on the insulator substrate; a gate insulator film [73] provided above the insulator substrate and the gate electrode; and a polycrystalline silicon film [74, 176] located on the gate insulator film, the polycrystalline silicon film being formed by laser annealing step on a surface of an amorphous layer; the gate electrode having a center portion with a flat surface.

Tsai et al. differs from the claimed invention by not showing a pair of tapered end portions with inclined surfaces and an angle between each of the inclined surfaces of the pair of tapered end portions and a surface of the insulator substrate being set within a range of 5 to 40 degrees.

Ono et al. shows a tapered end portion with inclined surface and an angle between the inclined surface of the tapered end portion and a surface of the insulator substrate being set to a range of 6 to 10 degrees (col. 18, lines 1-11).

Since both Tsai et al. and Ono et al. teach a thin film transistor with a bottom gate electrode, it would have been obvious to have the tapered end portion of the gate electrode of Ono et al. in each side of the gate electrode of Tsai et al. because it prevents the crack of the overlaying portion of the insulating film.

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It is inherent that the combined device would show a uniform grain size of the polycrystalline silicon film is acquired by securing a gate withstand voltage of the thin film transistor and preventing the inclined surfaces of the pair of tapered end portions from increasing. It is also inherent that the laser beam is scanned on the surface of the amorphous silicon film such that laser energy increases in order of the substrate, one of the pair of tapered end portions, and the center portion.

The process limitation of how the polycrystalline silicon film is formed have no patentable weight in claim drawn to structure. It is important to note that there are many ways to form a polycrystalline silicon film. Therefore, the phrases "formed by irradiating a laser beam on a surface of an amorphous silicon film to heat the amorphous film" and "the laser beam is scanned on the surface of the amorphous silicon film such that laser energy increases in order of the substrate, one of the pair of tapered end portions, and the center portion" are thus non-limiting.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Steven Loke whose telephone number is (703) 308-4920. The examiner can normally be reached on 7:45 am to 5:15 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (703) 308-2772. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-7722 for After Final communications.

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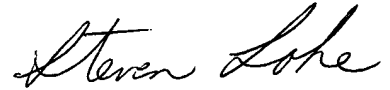
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Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

sl
September 30, 2001

Steven Loke
Primary Examiner

A handwritten signature in cursive script that reads "Steven Loke".